

C.V. RAMAN POLYTECHNIC, BBSR



LESSON PLAN

Session (2026-2027)

Discipline: Diploma Branch: ETC	Semester: 3rd	Name of the Teaching Faculty: Sabyasachi Patra Email ID: sabyasachi.patra@cvrp.edu.in
Subject: Electronics-Devices (ETCPC 203)	No. of Days/per week class allotted: 45days/ 3 class per week	Semester From Date: 01/07/2026 To Date:05/11/2026 No. of Weeks:15
Week	Class Day	Theory
1 st	1 st	1.1 Review of Quantum Mechanics
	2 nd	1.2 Electrons in Periodic Lattices
	3 rd	1.3 Energy Bands in Intrinsic & Extrinsic Si
2 nd	1 st	1.4.1 Diffusion Current
	2 nd	1.4.2 Drift Current
	3 rd	1.4.3 Mobility and Resistivity
3 rd	1 st	2.1 Generation and Recombination
	2 nd	2.2 Poisson and Continuity Equations
	3 rd	2.3.1 Construction of P-N Junction Diode
4 th	1 st	2.3.2 Operating Principle
	2 nd	2.3.3 P-N Junction Characteristics
	3 rd	2.3.4 I-V Characteristics
5 th	1 st	2.3.5 Small Signal Switching Models
	2 nd	2.3.6 Avalanche Breakdown

	3 rd	2.3.7 Zener Diode
6 th	1 st	2.3.8 Schottky Diode
	2 nd	2.3.9 LED
	3 rd	2.3.10 Photodiode and Solar Cell
7 th	1 st	3.1 Construction of BJT
	2 nd	3.2 Operating Principle of BJT, 3.3 Types of BJT
	3 rd	Class Test-1
8 th	1 st	3.4 Working of p-n-p & n-p-n BJT
	2 nd	3.5 I-V Characteristics
	3 rd	3.6 Ebers Moll Model
9 th	1 st	3.7 CB, CE, CC Configurations
	2 nd	3.8 Input & Output Characteristics
	3 rd	3.9 Alpha, Beta, Gamma Definitions
10 th	1 st	3.10 Mathematical Relationship
	2 nd	3.11, 3.12 Biasing and Types
	3 rd	3.13 h-Parameter Model
11 th	1 st	3.14 Load Line, Q-Point
	2 nd	3.15 Types of Coupling
	3 rd	3.16 R-C Coupled Amplifier
12 th	1 st	3.17 Frequency Response
	2 nd	4.1, 4.2 FET Intro & BJT vs JFET
	3 rd	4.3 JFET Construction & Operation
13 th	1 st	4.4 JFET Parameters
	2 nd	4.5 JFET as Amplifier, MOSFET Intro
	3 rd	4.6 MOSFET Classification, 4.7 MOSFET Characteristics

14 th	1 st	Class Test-2
	2 nd	4.8 CMOS, VMOS, LDMOS
	3 rd	5.1 Define & Classify Feedback Amplifier, 5.2 Feedback Amplifier & Types, 5.3 Characteristics of Amplifiers, 5.4 Oscillators & Barkhausen Criterion
15 th	1 st	5.5.1 to 5.5.3 LC oscillator, Colpitts, Hartley, Wien bridge oscillator. 6.1 Oxidation, 6.2 Diffusion
	2 nd	6.3 Ion implantation. 6.4 Photo-lithography 6.5 Etching
	3 rd	6.6 Chemical vapor deposition 6.7 Sputtering 6.8 Twin-tub CMOS process


Signature of Faculty


Signature of HOD (ETC)